PNP/NPN Epitaxial Planar Silicon Transistors



# 2SA1768/2SC4612

# **High-Voltage Switching Applications**

### **Applicaitons**

· Color TV sound output, converter, inverter.

### **Features**

- · Adoption of MBIT process.
- · High breakdown voltage, large current capacity.
- · Fast switching speed.

(): 2SA1768

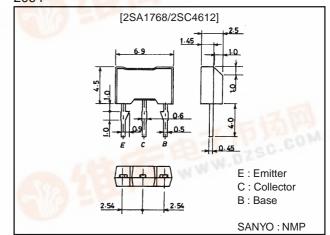
### **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

# **Package Dimensions**

unit:mm

2064



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)180	V
Collector-to-Emitter Voltage	VCEO		(-)160	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	10	(-)6	V
Collector Current	IC		(-)0.7	mA
Collector Current (Pulse)	ICP	4 FT 124	(–)1.5	mA
Collector Dissipation	PC	1		W
Junction Temperature	Tj	00/1/0	150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
Falametel	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)120V, I <sub>E</sub> =0			-0.1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			-0.1	μΑ
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)100mA	100*		400*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)10mA	90		40.3	101
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =-50mA		120		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz	44.4	(11)8		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =250mA, I <sub>B</sub> =(-)25mA		(-0.2)	(-0.5)	V
		red Falls		0.12	0.4	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =250mA, I <sub>B</sub> =(-)25mA		(–)0.85	(-)1.2	V

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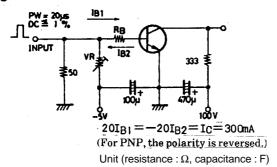
### 2SA1768/2SC4612

Parameter	Symbol	Conditions	Ratings			Unit
Farameter	Symbol	Conditions	min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0	(–)180			V
Collector-to-Emitter Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	(–)160			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0	6			V
Turn-ON Time	ton	See specified Test Circuit		(60)50		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(900)		ns
				1000		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		(60)60		ns

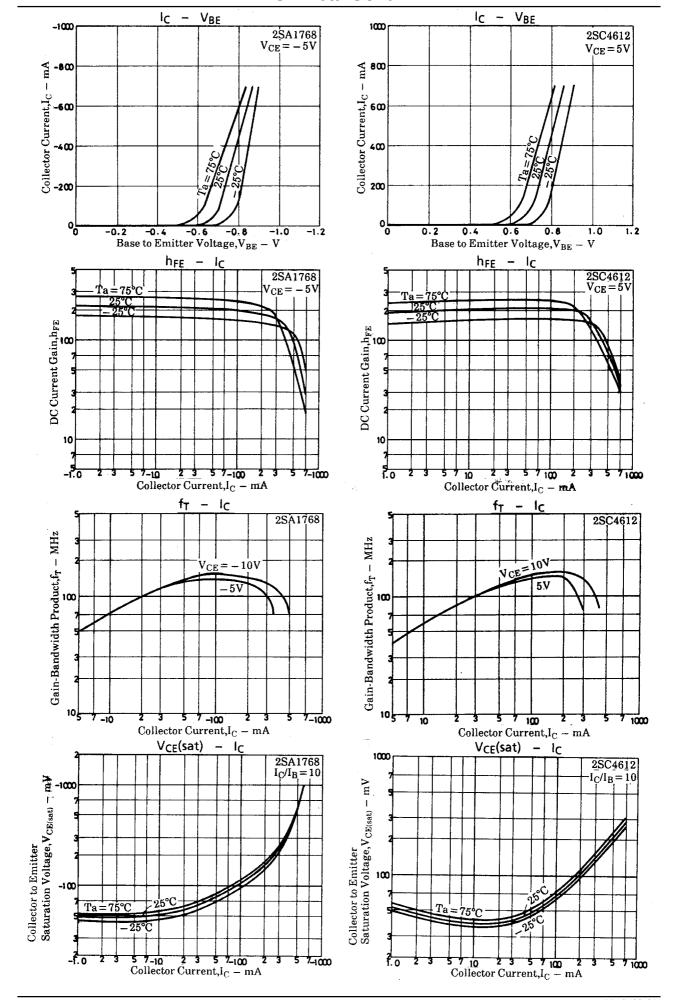
 $\mbox{*}$  : The 2SA1768/2SC4612 are classified by 100mA  $\mbox{h}_{FE}$  as follows :

100 R 200 140 S 280 200 T 40
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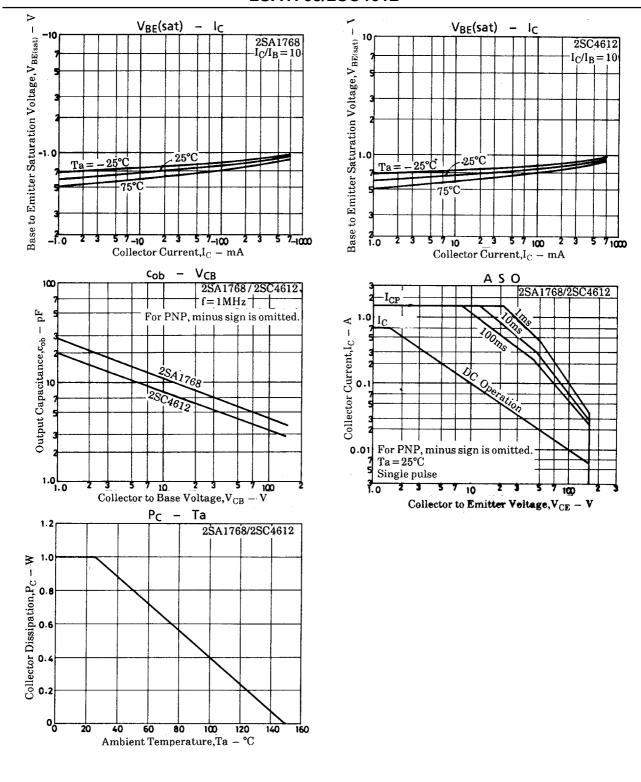
### **Switching Time Test Circuit**



 $V_{CE}$ lc VCE -800 From top From top 2SC4612 2SA1768 - 200mA 100mA -700 700 MAD -180mA 100mA €-600 90mA -160mA Collector Current, I<sub>C</sub> - IP 600 -80mA 40mA 80mA -140mA 70mA 30mA 60mA 500 60mA Collector Current,Ic 20mA - 40mA 400 20mA 10mA 300 200 100 -100  $I_B\!=\!0$ 0  $\begin{array}{cccc} \textbf{-200} & \textbf{-400} & \textbf{-600} & \textbf{-800} \\ \textbf{Collector to Emitter Voltage}, \textbf{V}_{CE} - \textbf{mV} \end{array}$ VCE ١c lc  $V_{CE}$ -800 1000 2SC4612 2SA1768 - 700 OmA 5mA 800 Collector Current, Ic - mA ¥ - 600 3.5mA 3.0mA Collector Current,I<sub>C</sub> - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 - 200 -600 2.0mA 2.0mA 400 1.5mA 1.5mA - 1.0mA 1.0mA 200 0.5 mA0.5mA -100  $I_B = 0$ 0 ō



## 2SA1768/2SC4612



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